## NSN 5962-01-351-5724

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View Online at https://aerobasegroup.com/nsn/5962-01-351-5724

Overall Height:
0.400 inches
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set an/sps-4 (v) 7
Features Provided:
Hermetically sealed and burn in and monolithic and electrostatic sensitive and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
output Logic Form
Complementary-metal oxide-semiconductor logic
Complementary-metal oxide-semiconductor logic
Complementary-metal oxide-semiconductor logic  Input Circuit Pattern:
Complementary-metal oxide-semiconductor logic  Input Circuit Pattern:  22 input
Complementary-metal oxide-semiconductor logic Input Circuit Pattern: 22 input Case Outline Source And Designator:
Complementary-metal oxide-semiconductor logic Input Circuit Pattern: 22 input Case Outline Source And Designator: D-9 mil-m-38510
Complementary-metal oxide-semiconductor logic  Input Circuit Pattern:  22 input  Case Outline Source And Designator:  D-9 mil-m-38510  Current Rating Per Characteristic:
Complementary-metal oxide-semiconductor logic Input Circuit Pattern: 22 input Case Outline Source And Designator: D-9 mil-m-38510 Current Rating Per Characteristic: 100.00 milliamperes reverse current, dc absolute
Complementary-metal oxide-semiconductor logic  Input Circuit Pattern:  22 input  Case Outline Source And Designator:  D-9 mil-m-38510  Current Rating Per Characteristic:  100.00 milliamperes reverse current, dc absolute  Terminal Surface Treatment:
Complementary-metal oxide-semiconductor logic  Input Circuit Pattern:  22 input  Case Outline Source And Designator:  D-9 mil-m-38510  Current Rating Per Characteristic:  100.00 milliamperes reverse current, dc absolute  Terminal Surface Treatment:  Solder
Complementary-metal oxide-semiconductor logic  Input Circuit Pattern:  22 input  Case Outline Source And Designator:  D-9 mil-m-38510  Current Rating Per Characteristic:  100.00 milliamperes reverse current, dc absolute  Terminal Surface Treatment:  Solder  Product Name:
Complementary-metal oxide-semiconductor logic Input Circuit Pattern: 22 input Case Outline Source And Designator: D-9 mil-m-38510 Current Rating Per Characteristic: 100.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Product Name: And-or-logic array

Time Rating Per Chacteristic: 25.00 nanoseconds delay

10.00 input picofarads and 10.00 output picofarads

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**Memory Device Type:** 

Pal

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Test	Data	Docu	ıment
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0